

S71WS-R based MCP Products

1.8 Volt-only x16 Simultaneous Read/Write, Burst Mode Flash Memory with CellularRAM

Data Sheet (Advance Information)



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Some data sheets contain a combination of products with different designations (Advance Information, Preliminary, or Full Production). This type of document distinguishes these products and their designations wherever necessary, typically on the first page, the ordering information page, and pages with the DC Characteristics table and the AC Erase and Program table (in the table notes). The disclaimer on the first page refers the reader to the notice on this page.

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When a product has been in production for a period of time such that no changes or only nominal changes are expected, the Preliminary designation is removed from the data sheet. Nominal changes may include those affecting the number of ordering part numbers available, such as the addition or deletion of a speed option, temperature range, package type, or V_{IO} range. Changes may also include those needed to clarify a description or to correct a typographical error or incorrect specification. Spansion Inc. applies the following conditions to documents in this category:

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Questions regarding these document designations may be directed to your local sales office.

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Data Sheet (Advance Information)

Features

- Power supply voltage of 1.7 to 1.95V
- Flash access time: 80 ns
- Flash burst frequencies: 80 MHz, 104 MHz
- pSRAM Access time: 70 ns
- pSRAM burst frequency: 104 MHz
- Package:
 - 8.0 x 11.6 mm MCP
- Operating Temperature
 - –30°C to +85°C (wireless)

The S71WS-R series is a product line of stacked packages and consists of:

- One or two S29WS-R NOR flash memory die
- CellularRAM die

The products covered by this document are listed in the table below.

Flash Device	CellularRAM Density (Mb)			
	32 Mb	64 Mb	128 Mb	256 Mb (2 x 128 Mb)
S29WS512R	—	—	S71WS512RD0	S71WS512RE0
S29WS256R	—	S71WS256RC0	S71WS256RD0	—
S29WS128R	S71WS128RB0	S71WS128RC0	—	—

Note:

For a full list of OPNs, please contact the local sales representative or refer to the Ordering Information valid combinations tables.

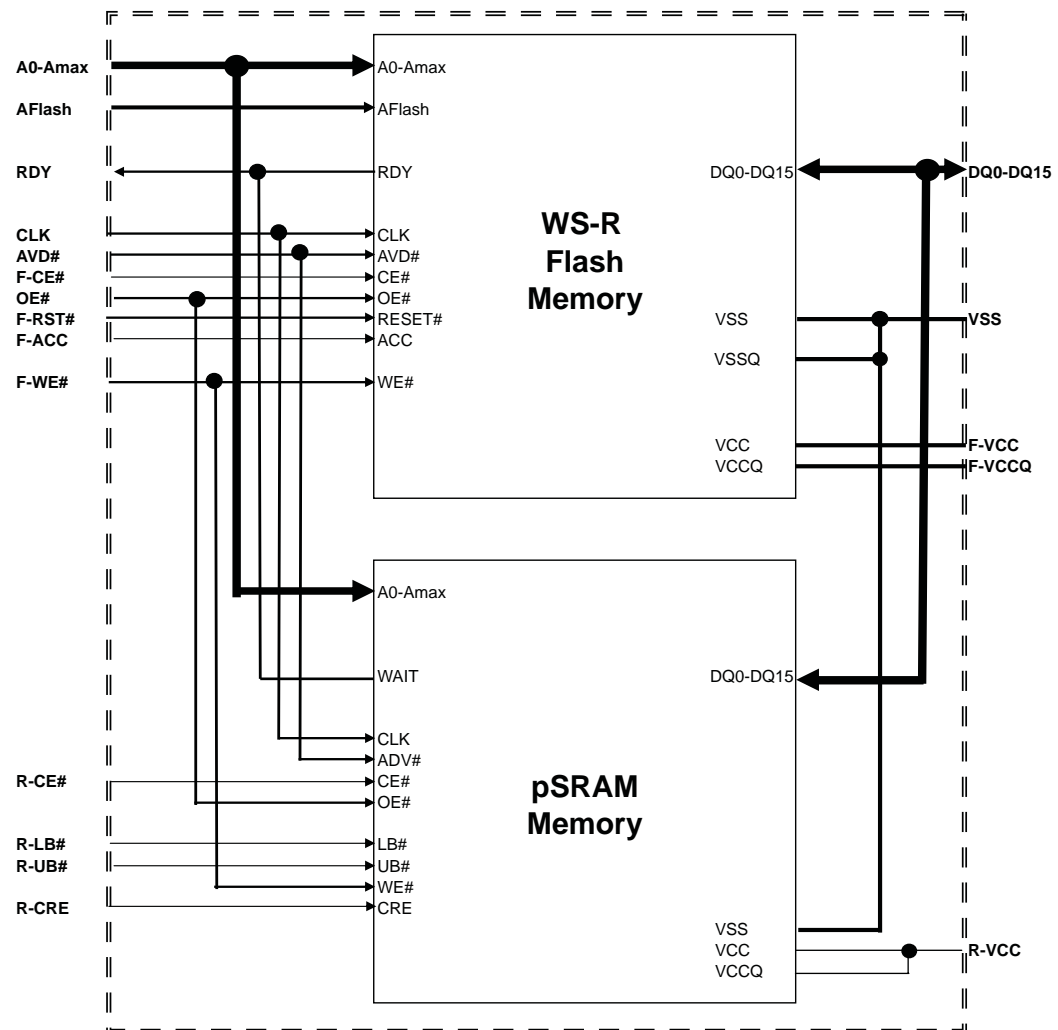
For detailed specifications, please refer to the individual data sheets.

Document	Publication Identification Number (PID)
S29WS-R	S29WS-R_00
128 Mb CellularRAM Type 5	custcomspec_00
128 Mb/64 Mb CellularRAM Type 2	Cellram_07
32 Mb CellularRAM Type 2	CellularRAM_08

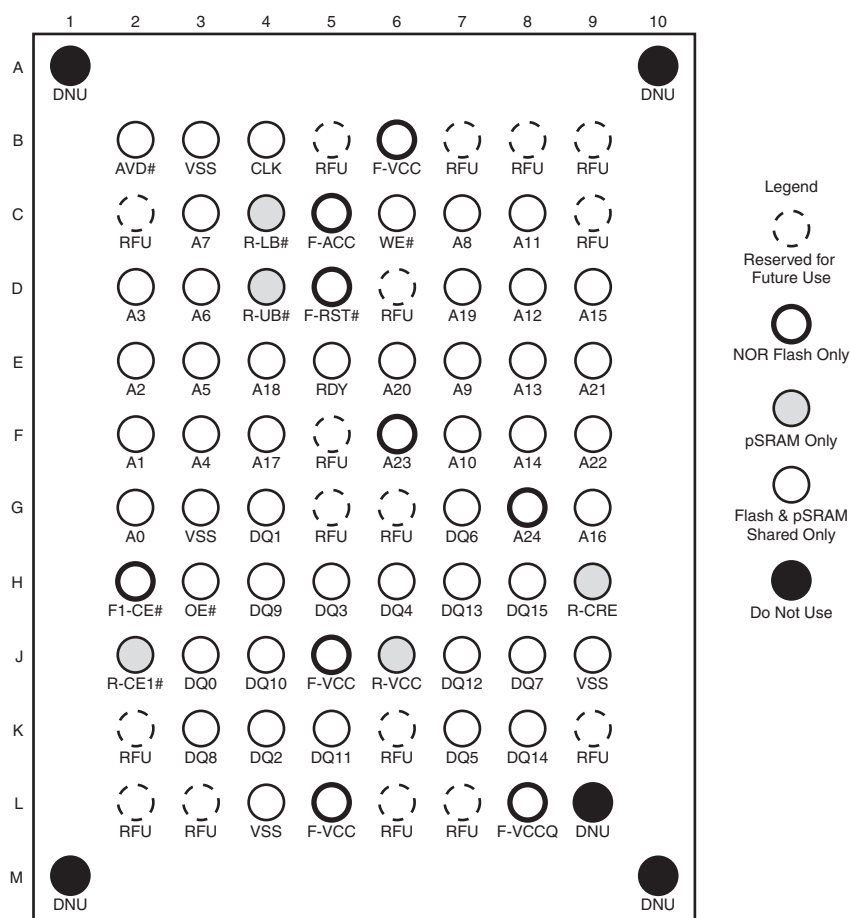
1. Product Selector Guide

Device	Model Number	Flash Density (Mb)	CellularRAM Density (Mb)	Flash Speed (MHz)	CellularRAM Speed (MHz)	CellularRAM Supplier	Package	Flash Boot Option
S71WS512RE0HH3	29	512	256	104	104	Type 2	84 ball MCP 8 x 11.6 x 1.4mm	Top Boot
S71WS512RE0HH3	09							Uniform Boot
S71WS512RD0HH3	29		128	Type 5			84 ball MCP 8x11.6x1.2mm	Top Boot
S71WS512RD0HH3	2A							Uniform Boot
S71WS512RD0HH3	09					80		Top Boot
S71WS512RD0HH3	0A					104		Uniform Boot
S71WS512RD0HH3	2S					80		Top Boot
S71WS512RD0HH3	2T					104		Uniform Boot
S71WS512RD0HH3	0S					80		Top Boot
S71WS512RD0HH3	0T					104		Uniform Boot
S71WS256RD0HH3	29	256	128			Type 2		Top Boot
S71WS256RD0HH3	2A							80
S71WS256RD0HH3	09			104				Top Boot
S71WS256RD0HH3	0A			80				Uniform Boot
S71WS256RC0HH3	29		64	104				Top Boot
S71WS256RC0HH3	2A			80				Uniform Boot
S71WS256RC0HH3	09			104				Top Boot
S71WS256RC0HH3	0A			80				Uniform Boot
S71WS128RC0HH3	29	128		104				Top Boot
S71WS128RC0HH3	2A			80				Uniform Boot
S71WS128RC0HH3	09			104				Top Boot
S71WS128RC0HH3	0A			80				Uniform Boot
S71WS128RB0HH3	29		32	104				Top Boot
S71WS128RB0HH3	2A			80				Uniform Boot
S71WS128RB0HH3	09			104				Top Boot
S71WS128RB0HH3	0A			80				Uniform Boot

2. MCP Block Diagram



3. Connection Diagrams



Note

1. V_{CC} pins must ramp simultaneously.

MCP	Flash-only Addresses	Shared Addresses
S71WS512RE0	A24	A23-A0
S71WS512RD0	A24-A23	A22-A0
S71WS256RD0	A23	A22-A0
S71WS256RC0	A23-A22	A21-A0
S71WS128RC0	A22	A21-A0
S71WS128RB0	A22-A21	A20-A0

3.1 Special Handling Instructions For FBGA Package

Special handling is required for Flash Memory products in FBGA packages.

Flash memory devices in FBGA packages may be damaged if exposed to ultrasonic cleaning methods. The package and/or data integrity may be compromised if the package body is exposed to temperatures above 150°C for prolonged periods of time.

3.2 Look-ahead Ballout for Future Designs

Please refer to the Design-in Scalable Wireless Solutions with Spansion Products application note (publication number: Design_Scalable_Wireless_A0_E). Contact your local Spansion sales representative for more details.

3.3 NOR Flash and pSRAM Input/Output Descriptions

Signal	Description	Flash	pSRAM
Amax-A0	NOR Flash/pSRAM Address inputs	X	X
DQ15-DQ0	Flash Data input/output, shared between NOR and pSRAM	X	X
F-CE#	NOR Flash Chip-enable input #1. Asynchronous relative to CLK for Burst Mode.	X	
OE#	Output Enable input. Asynchronous relative to CLK for Burst mode.	X	X
WE#	Write Enable input.	X	X
F-V _{CC}	NOR Flash device power supply (1.7 V - 1.95 V).	X	
F-V _{CCQ}	Input/Output Buffer power supply.	X	
V _{SS}	Ground	X	X
RFU	Reserved for Future Use		
RDY	Flash ready output. Indicates the status of the Burst read. V _{OL} = data valid. The Flash RDY pin is shared with the WAIT pin of the pSRAM.	X	X
CLK	NOR Flash Clock, shared with CLK of burst-mode pSRAM.. The first rising edge of CLK in conjunction with AVD# low latches the address input and activates burst mode operation. After the initial word is output, subsequent rising edges of CLK increment the internal address counter. CLK should remain low during asynchronous access.	X	X
AVD#	NOR Flash Address Valid input. Shared with AVD# of burst-mode pSRAM. Indicates to device that the valid address is present on the address inputs. V _{IL} = for asynchronous mode, indicates valid address; for burst mode, causes starting address to be latched on rising edge of CLK. V _{IH} = device ignores address inputs	X	X
F-RST#	NOR Flash hardware reset input. V _{IL} = device resets and returns to reading array data	X	
F-ACC	NOR Flash accelerated input. At V _{IH} , accelerates programming; automatically places device in unlock bypass mode. At V _{IL} , disables all program and erase functions. Should be at V _{IH} for all other conditions.	X	
R-CE#	Chip-enable input for pSRAM		X
R-CRE	Control Register Enable (pSRAM). For CellularRAM only.		X
R-VCC	pSRAM Power Supply		X
R-UB#	Upper Byte Control (pSRAM)		X
R-LB#	Lower Byte Control (pSRAM)		X
DNU	Do Not Use		

4. Ordering Information

The order number is formed by a valid combinations of the following:

S71WS	512	R	E0	HH	3	2	9	0
PACKING TYPE 0 = Tray 2 = 7" Tape and Reel 3 = 13" Tape and Reel								
FLASH SPEED 9 = 104 MHz Flash Speed, CellularRAM Type 2 A = 80 MHz Flash Speed, CellularRAM Type 2 S = 104 MHz Flash Speed, CellularRAM Type 5 T = 80 MHz Flash Speed, CellularRAM Type 5								
FLASH BOOT OPTION 2 = Top Boot 0 = Uniform Boot								
PACKAGE DESCRIPTOR 3 = 8 x11.6 mm Package Area, 84-Ball, 0.45 mm Raw Ball Size								
PACKAGE TYPE & MATERIAL SET HH = 1.2 mm MCP FBGA, Pb-free, low-Halogen								
CellularRAM DENSITY E0 = 256 Mb D0 = 128 Mb C0 = 64 Mb B0 = 32 Mb								
PROCESS TECHNOLOGY R = 65 nm, MirrorBit® Technology								
CODE FLASH DENSITY 512 = 512 Mb 256 = 256 Mb 128 = 128 Mb								
PRODUCT FAMILY S71WS Stacked Products (MCP/PoP) 1.8 V NOR Flash with pSRAM								

4.1 Valid Combinations

Valid Combinations list configurations planned to be supported in volume for this device. Consult your local sales office to confirm availability of specific valid combinations and to check on newly released combinations.

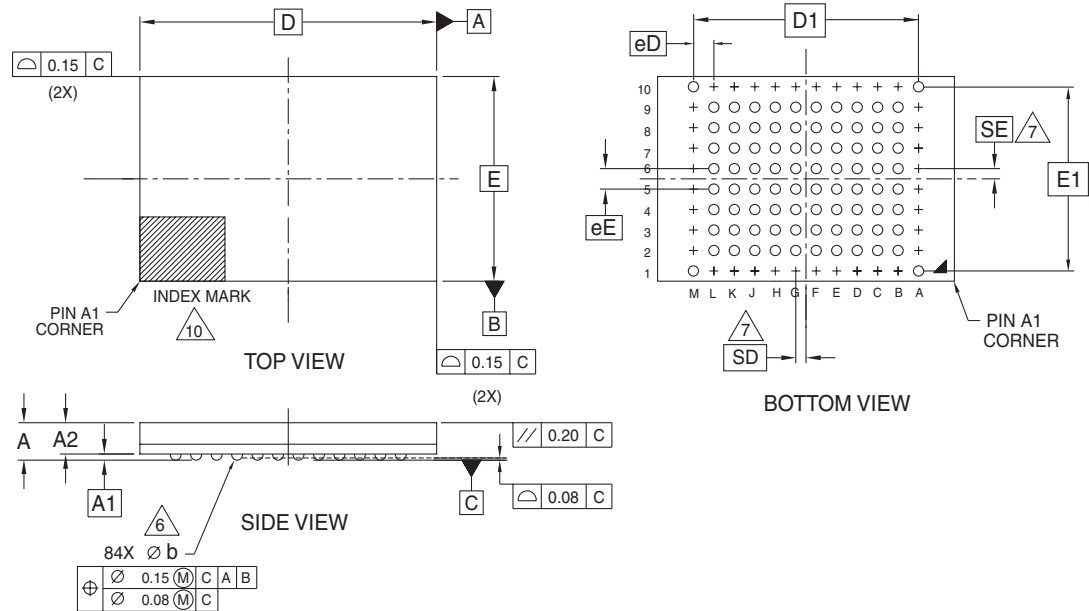
Valid Combination							
Product Family	Code Flash Denisty (Mb)	Process Technology	CellularRAM Density	Package Type / Material	Flash Boot Option	Flash Speed	Packing Type
S71WS	128	R	B0, C0	HH3	2, 0	9, A	0,2,3 (Note 1)
	256		C0, D0				
	512		D0			9, A, S, T	
			E0				

Notes:

- Packing Type 0 is standard. Specify other options as required.
- BGA package marking omits leading S and packing type designator from ordering part number.

5. Physical Dimensions

5.1 8 x 11.6 x 1.4 mm— 84-ball Fine Pitch Ball Grid Array (FBGA) Package

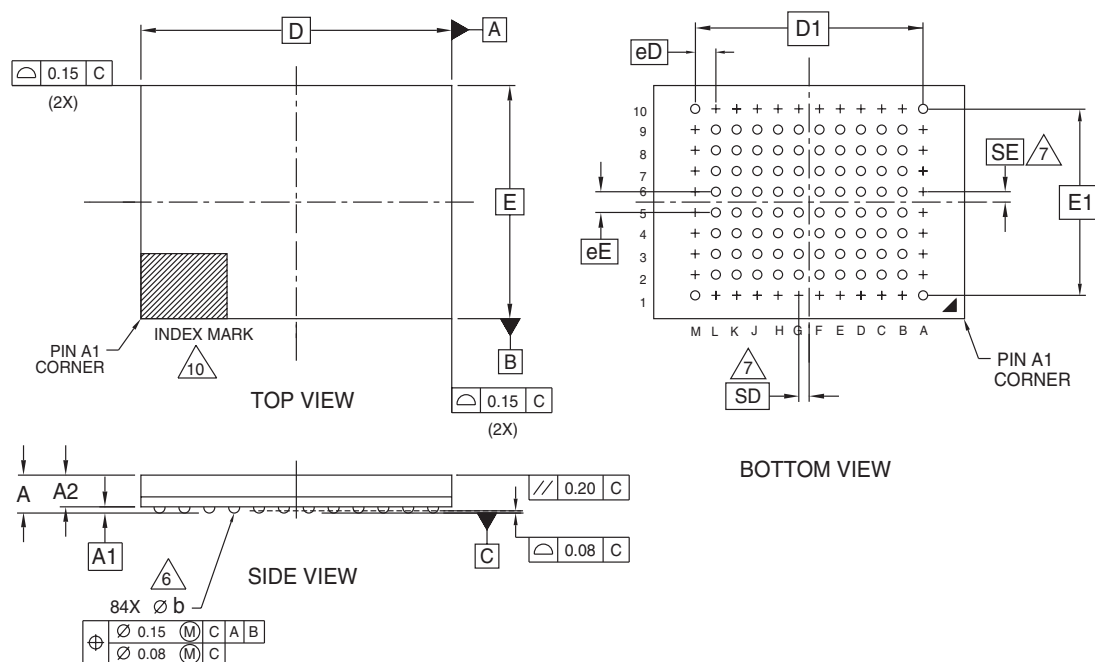








NOTES:

- DIMENSIONING AND TOLERANCING METHODS PER ASME Y14.5M-1994.
- ALL DIMENSIONS ARE IN MILLIMETERS.
- BALL POSITION DESIGNATION PER JESD 95-1, SPP-010.
- \boxed{e} REPRESENTS THE SOLDER BALL GRID PITCH.
- SYMBOL "MD" IS THE BALL MATRIX SIZE IN THE "D" DIRECTION.
SYMBOL "ME" IS THE BALL MATRIX SIZE IN THE "E" DIRECTION.
n IS THE NUMBER OF POPULATED SOLDER BALL POSITIONS FOR MATRIX SIZE MD X ME.
- DIMENSION "b" IS MEASURED AT THE MAXIMUM BALL DIAMETER IN A PLANE PARALLEL TO DATUM C.
- SD AND SE ARE MEASURED WITH RESPECT TO DATUMS A AND B AND DEFINE THE POSITION OF THE CENTER SOLDER BALL IN THE OUTER ROW.
WHEN THERE IS AN ODD NUMBER OF SOLDER BALLS IN THE OUTER ROW SD OR SE = 0.000.
WHEN THERE IS AN EVEN NUMBER OF SOLDER BALLS IN THE OUTER ROW, SD OR SE = $\frac{e}{2}$.
- "+" INDICATES THE THEORETICAL CENTER OF DEPOPULATED BALLS.
- N/A
- A1 CORNER TO BE IDENTIFIED BY CHAMFER, LASER OR INK MARK, METALLIZED MARK INDENTATION OR OTHER MEANS.

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5.2 8 x 11.6 x 1.2 mm— 84-ball Fine Pitch Ball Grid Array (FBGA) Package



PACKAGE	TLA 084			
JEDEC	N/A			
D x E	11.60 mm x 8.00 mm PACKAGE			
SYMBOL	MIN	NOM	MAX	NOTE
A	---	---	1.20	PROFILE
A1	0.17	---	---	BALL HEIGHT
A2	0.81	---	0.97	BODY THICKNESS
	11.60 BSC.			BODY SIZE
	8.00 BSC.			BODY SIZE
	8.80 BSC.			MATRIX FOOTPRINT
	7.20 BSC.			MATRIX FOOTPRINT
MD	12			MATRIX SIZE D DIRECTION
ME	10			MATRIX SIZE E DIRECTION
n	84			BALL COUNT
Ø b	0.35	0.40	0.45	BALL DIAMETER
	0.80 BSC.			BALL PITCH
	0.80 BSC.			BALL PITCH
SD / SE	0.40 BSC.			SOLDER BALL PLACEMENT
	A2,A3,A4,A5,A6,A7,A8,A9 B1,B10,C1,C10,D1,D10, E1,E10,F1,F10,G1,G10, H1,H10,J1,J10,K1,K10,L1,L10, M2,M3,M4,M5,M6,M7,M8,M9			DEPOPULATED SOLDER BALLS

NOTES:

- DIMENSIONING AND TOLERANCING METHODS PER ASME Y14.5M-1994.
- ALL DIMENSIONS ARE IN MILLIMETERS.
- BALL POSITION DESIGNATION PER JESD 95-1, SPP-010.
- [e] REPRESENTS THE SOLDER BALL GRID PITCH.
- SYMBOL "MD" IS THE BALL MATRIX SIZE IN THE "D" DIRECTION.
SYMBOL "ME" IS THE BALL MATRIX SIZE IN THE "E" DIRECTION.
n IS THE NUMBER OF POPULATED SOLDER BALL POSITIONS FOR MATRIX SIZE MD X ME.
- DIMENSION "b" IS MEASURED AT THE MAXIMUM BALL DIAMETER IN A PLANE PARALLEL TO DATUM C.
- SD AND SE ARE MEASURED WITH RESPECT TO DATUMS A AND B AND DEFINE THE POSITION OF THE CENTER SOLDER BALL IN THE OUTER ROW.
- WHEN THERE IS AN ODD NUMBER OF SOLDER BALLS IN THE OUTER ROW SD OR SE = 0.000.
WHEN THERE IS AN EVEN NUMBER OF SOLDER BALLS IN THE OUTER ROW, SD OR SE = [e/2]
- "+" INDICATES THE THEORETICAL CENTER OF DEPOPULATED BALLS.
- N/A
- A1 CORNER TO BE IDENTIFIED BY CHAMFER, LASER OR INK MARK, METALLIZED MARK INDENTATION OR OTHER MEANS.

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6. Revision History

Section	Description
Revision 01 (April 14, 2008)	
	Initial release
Revision 02 (May 20, 2008)	
Global	Added S71WS128RC0
Product Selector Guide	Updated model numbers for all OPNs
Ordering Information	Updated model numbers for all OPNs
Valid Combinations	Updated model numbers for all OPNs
Revision 03 (November 19, 2008)	
Global	Updated S71WS512RD0HH3 Added OPNs S71WS512RE0HH329/09
Product Selector Guide	Updated model numbers for all OPNs
Ordering Information	Updated model numbers for all OPNs

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